- An InGaAs p-i-n photodiode has the following . parameters at a wavelength of 1310 nm -  $I_D = 4 nA$ ,  $\cdot$   $\eta = 0.90$  ,  $R_L = 1000~\Omega$  and surface leakage current is negligible. The incident power is 200 µw, and the receiver bandwidth is 200 MHz. Find various terms of the receiver.
- Explain the impact ionization in Avalanche photodiodes. Define photomultiplication factor and cutoff wavelength of photodiode.
- Attempt any two of the following:  $10 \times 2 = 20$ 
  - (a) Explain the major elements of an optical fiber receiver. Describe the usage of preamplifier and technique for automatic gain control in APD receiver.
  - What is coherent detection? How many kinds of coherent detection system may be designed? Explain the advantage of coherent detection system over the direct detection system.
  - Explain link power budget. A 5 km length optical fiber link has a fiber cable which has an attenuation of 4 dB km<sup>-1</sup>. The splices are 0.7 dB km<sup>-1</sup> and connector losses at the source and detectors are 4 and 3.5. Considering no dispersion on the link, calculate the total channel loss
  - Explain the following terms:
    - ASK, FSK, PSK modulation
    - System design consideration for optical fiber communication.



## B. Tech.

## (SEM. VII) EXAMINATION, 2008-09 OPTICAL FIBER COMMUNICATION

Time: 3 Hours] Note:

- Attempt all questions.
- All questions carry equal marks.
- Be precise in your answer.
- No second answer book will be provided.

[Total Marks : 100

- Attempt any four of the following:  $5 \times 4 = 20$ 
  - What is the structure of an optical fiber ? Give advantages of optical fiber over metallic cables.
  - What is difference between single mode and multimode fiber? Find the NA and core radius of the fiber for a single mode fiber operating at 1300 nm with  $n_{core} = 1.5$  and  $n_{clad} = 1.45$ .
  - Prove that propagation constant of an optical fiber is the product of free space propagation constant and the rms value of its core-cladding refractive indices. Given normalized propagation constant is half (1/2).
  - Calculate the number of modes at 820 nm and 1.3 µm in graded index fiber having a parabolic index profile  $(\alpha = 2)$ , a 25  $\mu m$  core radius,  $n_1 = 1.48$  and  $n_2 = 1.46$ . How does this compare to a step index fiber ?

- (e) Explain the importance of mode field diameter for single mode fiber, with suitable diagram.
- (f) A step index fiber is constructed with  $n_1 = 1.450$ ,  $n_2 = 1.445$  and  $a = 4.0 \,\mu m$ .
  - (i) Will this fiber be single mode when the operating wavelength is  $\lambda = 1.55 \,\mu m$ ?
  - (ii) Evaluate the cutoff wavelength  $\lambda_c$  for  $\mathit{LP}_{11}$
- 2 Attempt any four of the following: 5×4=20
  (a) What is signal attenuation mechanism in a fiber?
  What is the unit of attenuation?
  - (b) A single mode fiber has an attenuation of 0.5 dB/km, when operating at a wavelength of 1310 nm. The core diameter is 8 μm and source bandwidth 500 MHz. Compute the threshold optical powers for stimulated Brillouin and Raman scattering.
  - (c) Explain what is meant by the critical bending radius for an optical fiber.
  - (d) Explain the mechanism of intermodal dispersion in a multimode step index fiber. And show that broadening of light pulse  $\delta T_s$  is given as  $\delta T_s = \frac{L(NA)^2}{2 n_1 c}$ .
  - (e) Describe dispersion shifted and dispersion flattened single mode fibers.
  - (f) Two fibers having same polarisation and operating at a wavelength of 0.8 μm have beat lengths of 0.5 mm and 75 m. Find the modal birefringence in each case and interpret the length.

- 3 Attempt any four of the following : 5×4=20
  - (a) What is the major advantage of heterostructure LED over a homostructured one? Calculate the cutoff wavelength of GaAs material with optical energy gap of 1.4 eV at 273 °K.
  - (b) Explain semiconductor injection laser. Find its internal quantum efficiency and show how it is related to the differential external quantum efficiency.
  - (c) Find the external power efficiency of GaAs planer LED having refractive index of 3.6 with transmission factor of GaAs air interface of 0.70. The internally generated optical power is 30% of the electric power supplied.
  - (d) What is the difference between a surface emitting LED and edge emitting LED. An injection laser has a total efficiency in the Gallium Arsenide active region as 20%. The voltage applied to the device is 2.2 volts. If the bandgap energy of GaAs is 1.43 eV, find the external power efficiency of the device.
  - (e) Find the number of longitudinal modes of a laser having a crystal length of 7 cm, refractive index 1.5 and peak emission wavelength of 0.5 μm. Also find their frequency separation.
  - (f) What does "FWHM" stand for ? How does it apply to an LED characteristics ?
- 4 Attempt any two of the following: 10×2=20
  - (a) What are the requirements of photodetector? Calculate the efficiency a PIN silicon photodiode if the responsivity is 0.374 AW<sup>-1</sup> at 1300 nm wavelength.
  - (b) How is silicon RAPD operated? How does it differ form P-i-n photodiode. What are the advantage and disadvantage of RAPD detector?